MMBV2101LT1 Series, MV2105, MV2101, MV2109, LV2209

Preferred Device

Silicon Tuning Diodes

These devices are designed in popular plastic packages for the high volume requirements of FM Radio and TV tuning and AFC, general frequency control and tuning applications. They provide solid–state reliability in replacement of mechanical tuning methods. Also available in a Surface Mount Package up to 33 pF.

Features

- High Q
- Controlled and Uniform Tuning Ratio
- Standard Capacitance Tolerance 10%
- Complete Typical Design Curves
- Pb–Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Reverse Voltage	V _R	30	Vdc	
Forward Current	١ _F	200	mAdc	
Forward Power Dissipation@ $T_A = 25^{\circ}C$ MMBV21xxDerate above $25^{\circ}C$ @@ $T_A = 25^{\circ}C$ MV21xxDerate above $25^{\circ}C$ LV2209	P _D	225 1.8 280 2.8	mW mW/°C mW mW/°C	
Junction Temperature	TJ	+150	°C	
Storage Temperature Range	T _{stg}	–55 to +150	°C	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

ELECTRICAL	CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)
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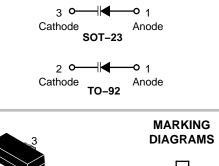
Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μAdc)	V _{(BR)R}				Vdc
MMBV21xx, MV21xx		30	-	-	
LV2209		25	-	-	
Reverse Voltage Leakage Current ($V_R = 25 \text{ Vdc}, T_A = 25^{\circ}\text{C}$)	I _R	-	-	0.1	μAdc
Diode Capacitance Temperature Coefficient ($V_R = 4.0 \text{ Vdc}, \text{ f} = 1.0 \text{ MHz}$)	TC _C	I	280	I	ppm/°C

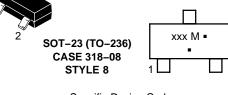


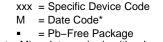
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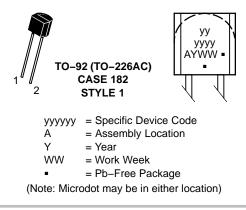
6.8–100 pF, 30 VOLTS VOLTAGE VARIABLE CAPACITANCE DIODES







(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

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				C _T , Diode Capacitance V _R = 4.0 Vdc, f = 1.0 MHz pF		Q, Figure of MeritTR, Tunir $V_R = 4.0$ Vdc, C_2/C f = 50 MHzf = 1.0		C2/C30	C ₃₀	
Device	Marking	Package	Shipping [†]	Min	Nom	Мах	Тур	Min	Тур	Max
MMBV2101LT1	M4G	SOT-23	3,000 / Tape & Reel	6.1	6.8	7.5	450	2.5	2.7	3.2
MMBV2101LT1G	M4G	SOT-23 (Pb-Free)	3,000 / Tape & Reel	6.1	6.8	7.5	450	2.5	2.7	3.2
MMBV2101L	M4G	SOT-23	Bulk (Note 1)	6.1	6.8	7.5	450	2.5	2.7	3.2
MV2101	MV2101	TO-92	1,000 per Box	6.1	6.8	7.5	450	2.5	2.7	3.2
MV2101G	MV2101	TO-92 (Pb-Free)	1,000 per Box	6.1	6.8	7.5	450	2.5	2.7	3.2
MMBV2103LT1	4H	SOT-23	3,000 / Tape & Reel	9.0	10	11	400	2.5	2.9	3.2
MMBV2105LT1	4U	SOT-23	3,000 / Tape & Reel	13.5	15	16.5	400	2.5	2.9	3.2
MMBV2105LT1G	4U	SOT-23 (Pb-Free)	3,000 / Tape & Reel	13.5	15	16.5	400	2.5	2.9	3.2
MMBV2105L	4U	SOT-23	Bulk (Note 1)	13.5	15	16.5	400	2.5	2.9	3.2
MV2105	MV2105	TO-92	1,000 per Box	13.5	15	16.5	400	2.5	2.9	3.2
MV2105G	MV2105	TO-92 (Pb-Free)	1,000 per Box	13.5	15	16.5	400	2.5	2.9	3.2
MMBV2107LT1	4W	SOT-23	3,000 / Tape & Reel	19.8	22	24.2	350	2.5	2.9	3.2
MMBV2107LT1G	4W	SOT-23 (Pb-Free)	3,000 / Tape & Reel	19.8	22	24.2	350	2.5	2.9	3.2
MMBV2107L	4W	SOT-23	Bulk (Note 1)	19.8	22	24.2	350	2.5	2.9	3.2
MMBV2108LT1	4X	SOT-23	3,000 / Tape & Reel	24.3	27	29.7	300	2.5	3.0	3.2
MMBV2108LT1G	4X	SOT-23 (Pb-Free)	3,000 / Tape & Reel	24.3	27	29.7	300	2.5	3.0	3.2
LV2209	LV2209	TO-92	1,000 per Box	29.7	33	36.3	200	2.5	3.0	3.2
MMBV2109LT1	4J	SOT-23	3,000 / Tape & Reel	29.7	33	36.3	200	2.5	3.0	3.2
MMBV2109LT1G	4J	SOT-23 (Pb-Free)	3,000 / Tape & Reel	29.7	33	36.3	200	2.5	3.0	3.2
MMBV2109L	4J	SOT-23	Bulk (Note 1)	29.7	33	36.3	200	2.5	3.0	3.2
MV2109	MV2109	TO-92	1,000 per Box	29.7	33	36.3	200	2.5	3.0	3.2
MV2109G	MV2109	TO-92 (Pb-Free)	1,000 per Box	29.7	33	36.3	200	2.5	3.0	3.2

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

1. MMBV2101LT1, MMBV2105LT1, MMBV2107LT1 thru MMBV2109LT1, are also available in bulk. Use the device title and drop the "T1" suffix when ordering any of these devices in bulk.

PARAMETER TEST METHODS

1. C_T, DIODE CAPACITANCE

 $(C_T = C_C + C_J)$. C_T is measured at 1.0 MHz using a capacitance bridge (Boonton Electronics Model 75A or equivalent).

2. TR, TUNING RATIO

TR is the ratio of C_T measured at 2.0 Vdc divided by C_T measured at 30 Vdc.

3. Q, FIGURE OF MERIT

Q is calculated by taking the G and C readings of an admittance bridge at the specified frequency and substituting in the following equations: (Boonton Electronics Model 33AS8 or equivalent). Use Lead Length $\approx 1/16''$.

4. TC_C, DIODE CAPACITANCE TEMPERATURE COEFFICIENT

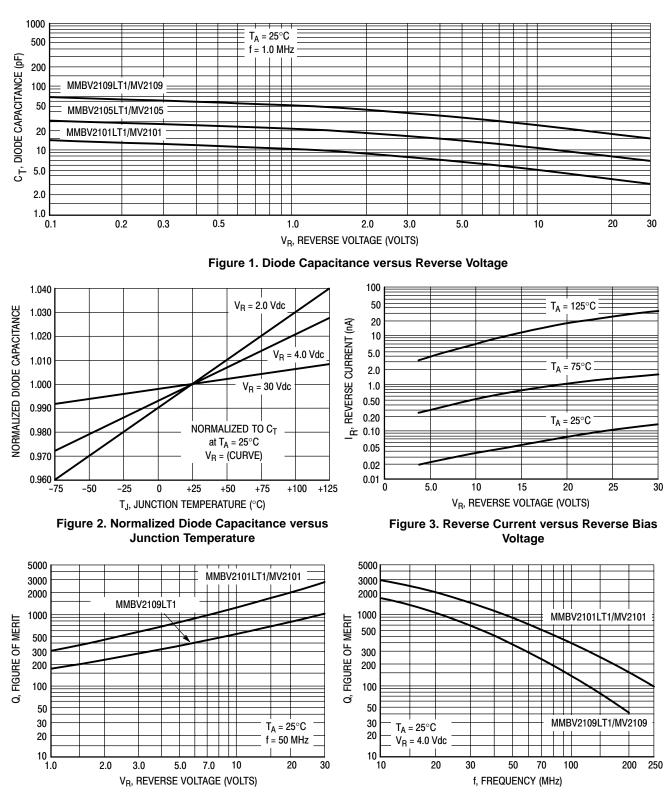
TC_C is guaranteed by comparing C_T at V_R = 4.0 Vdc, f = 1.0 MHz, T_A = -65°C with C_T at V_R = 4.0 Vdc, f = 1.0 MHz, T_A = +85°C in the following equation, which defines TC_C:

$$TC_{C} = \left| \frac{C_{T}(+85^{\circ}C) - C_{T}(-65^{\circ}C)}{85 + 65} \right| \cdot \frac{10^{6}}{C_{T}(25^{\circ}C)}$$

Accuracy limited by measurement of C_T to ± 0.1 pF.

 $Q = \frac{2\pi fC}{G}$

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TYPICAL DEVICE CHARACTERISTICS

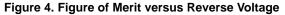
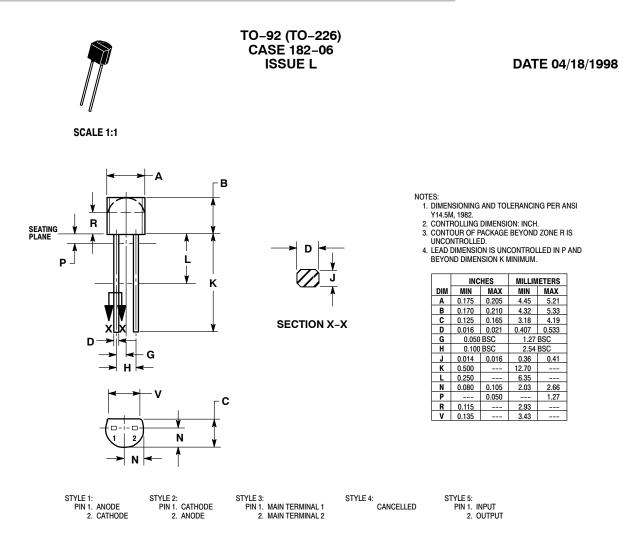


Figure 5. Figure of Merit versus Frequency

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





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PUBLICATION ORDERING INFORMATION

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ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative